Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
Between 0.165 inches and 0.185 inches
Terminal Length:
0.500 inches
Overall Diameter:
Between 0.335 inches and 0.370 inches
Component Name And Quantity:
2 transistor
Mounting Method:
Terminal
Terminal Circle Diameter:
0.200 inches
Semiconductor Material:
Silicon all transistor
Voltage Rating In Volts Per Characteristic:
35.0 drain to gate voltage all transistor and 35.0 drain to source voltage all transistor
Current Rating Per Characteristic:
1.00 milliamperes gate current all transistor
Power Rating Per Characteristic:
500.0 milliwatts total device dissipation all transistor
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Precious Material And Location:
Leads gold
Precious Material:
Gold
Terminal Type And Quantity:
8 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
 Demilitarization:
No
Fiig:
A110a0